onsemi

Dual Switching Diode BAS16DXV6

Features

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

Rating	Symbol	Max	Unit
Continuous Reverse Voltage	V _R	100	V
Recurrent Peak Forward Current	١ _F	200	mA
Peak Forward Surge Current Pulse Width = 10 μ s	I _{FM(surge)}	500	mA

THERMAL CHARACTERISTICS

Characteristic (One Junction Heated)	Symbol	Max	Unit
Total Device Dissipation (Note 1) $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	P _D	357 2.9	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	350	°C/W
Characteristic (Both Junctions Heated)	Symbol	Мах	Unit
Total Device Dissipation (Note 1) T _A = 25°C Derate above 25°C	P _D	500 4.0	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	250	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-4 @ Minimum Pad





MARKING DIAGRAM



A6 = Specific Device Code

M = Date Code

= Pb–Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
BAS16DXV6T1G	SOT–563 (Pb–Free)	4000 / Tape & Reel
SBAS16DXV6T1G	SOT–563 (Pb–Free)	4000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
Forward Voltage $(I_F = 1.0 \text{ mA})$ $(I_F = 10 \text{ mA})$ $(I_F = 50 \text{ mA})$ $(I_F = 150 \text{ mA})$	V _F	- - -	715 855 1000 1250	mV
Reverse Current $(V_R = 100 V)$ $(V_R = 75 V, T_J = 150^{\circ}C)$ $(V_R = 25 V, T_J = 150^{\circ}C)$	I _R	- - -	1.0 50 30	μΑ
Capacitance (V _R = 0, f = 1.0 MHz)	C _D	-	2.0	pF
Reverse Recovery Time (I _F = I _R = 10 mA, R _L = 50 Ω) (Figure 1)	t _{rr}	-	6.0	ns
Stored Charge (I _F = 10 mA to V _R = 6.0 V, R _L = 500 Ω) (Figure 2)	QS	-	45	PC
Forward Recovery Voltage (I _F = 10 mA, t _r = 20 ns) (Figure 3)	V _{FR}	-	1.75	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

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Figure 1. Reverse Recovery Time Equivalent Test Circuit



Figure 2. Stored Charge Equivalent Test Circuit



Figure 3. Forward Recovery Voltage Equivalent Test Circuit

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TYPICAL CHARACTERISTICS



Figure 4. Forward Voltage





Figure 6. Capacitance









SOT-563, 6 LEAD CASE 463A ISSUE H

DATE 26 JAN 2021

- NDTES: DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 1. CONTROLLING DIMENSION: MILLIMETERS 2.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH З. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS. THICKNESS OF BASE MATERIAL.



RECOMMENDED MOUNTING FOOTPRINT* For additional information on our Pb-Free ж strategy and soldering details, please download

the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

A		5X	
	I	' H _E	
		V	
-	- C		

SIDE VIEW

	MILLIMETERS		
DIM	MIN.	NDM.	MAX.
А	0.50	0.55	0.60
b	0.17	0.22	0.27
С	0.08	0.13	0.18
D	1.50	1.60	1.70
Е	1.10	1.20	1.30
e	0.50 BSC		
L	0.10	0.20	0.30
HE	1.50	1.60	1.70

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STYL PIN	E 1: 1. EMITTER 1 2. BASE 1 3. COLLECTOR 2 4. EMITTER 2 5. BASE 2 6. COLLECTOR 1	STYLE 2: PIN 1. EMITTER 1 2. EMITTER 2 3. BASE 2 4. COLLECTOR 2 5. BASE 1 6. COLLECTOR 1	STYLE 3: PIN 1. CATHODE 1 2. CATHODE 1 3. ANODE/ANODE 2 4. CATHODE 2 5. CATHODE 2 6. ANODE/ANODE 1
STYL PIN	E 4: 1. COLLECTOR 2. COLLECTOR 3. BASE 4. EMITTER 5. COLLECTOR 6. COLLECTOR	STYLE 5: PIN 1. CATHIDE 2. CATHIDE 3. ANIDE 4. ANIDE 5. CATHIDE 6. CATHIDE	STYLE 6: PIN 1. CATHODE 2. ANODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE
STYL PIN	E 7: 1. CATHEDE 2. ANEDE 3. CATHEDE 4. CATHEDE 5. ANEDE 6. CATHEDE	STYLE 8: PIN 1. DRAIN 2. DRAIN 3. GATE 4. SDURCE 5. DRAIN 6. DRAIN	STYLE 9: PIN 1. SDURCE 1 2. GATE 1 3. DRAIN 2 4. SDURCE 2 5. GATE 2 6. DRAIN 1
STYL PIN	E 10: 1. CATHEDE 1 2. N/C 3. CATHEDE 2 4. ANEDE 2 5. N/C	STYLE 11: PIN 1. EMITTER 2 2. BASE 2 3. COLLECTOR 1 4. EMITTER 1 5. BASE 1	

6. COLLECTOR 2

DATE 26 JAN 2021

GENERIC **MARKING DIAGRAM***



XX = Specific Device Code

M = Month Code

. = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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